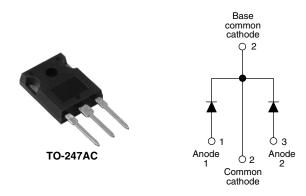


VS-63CPQ100GPbF, VS-63CPQ100G-N3

Vishay Semiconductors

Schottky Rectifier, 2 x 30 A



PRODUCT SUMMARY	PRODUCT SUMMARY								
Package	TO-247AC								
I _{F(AV)}	2 x 30 A								
V _R	100 V								
V _F at I _F	0.64 V								
I _{RM} max.	25 mA at 125 °C								
T _J max.	175 °C								
Diode variation	Common cathode								
E _{AS}	15 mJ								

FEATURES

- 175 °C T_J operation
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



- I RoHS COMPLIANT HALOGEN FREE
- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

The VS-63CPQ100G... center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform	60	A						
V _{RRM}		100	V						
I _{FSM}	t _p = 5 μs sine	2200	A						
V _F	30 Apk, T _J = 125 °C (per leg)	0.64	V						
TJ	Range	- 55 to 175	۵°						

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS-63CPQ100PbF	VS-63CPQ100-N3	UNITS					
Maximum DC reverse voltage	V _R	100	100	V					
Maximum working peak reverse voltage	V _{RWM}	100	100	V					

ABSOLUTE MAXIMUM RATINGS									
PARAMETER		SYMBOL	TEST COND	VALUES	UNITS				
Maximum average per leg			50 % duty cycle at $T_{e} = 153$ %	50 % duty cycle at T _C = 153 °C, rectangular waveform					
See fig. 5	per device	I _{F(AV)}	30% duty cycle at 10° = 100 $\%$	60	•				
	Maximum peak one cycle non-repetitive		5 µs sine or 3 µs rect. pulse Following any rated load condition and with		2200	A			
surge current per leg See fig. 7		I _{FSM}	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	410				
Non-repetitive avalanche energy per leg		E _{AS}	T _J = 25 °C, I _{AS} = 1 A, L = 30 mH		15	mJ			
Repetitive avalanche current per leg		I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _B typical		1	А			

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ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS				
		30 A	T.I = 25 °C	0.77	v				
Maximum forward voltage drop per leg See fig. 1	V _{FM} ⁽¹⁾	60 A	1j=25 C	0.92					
	VFM ()	30 A	T 105 %O	0.64					
		60 A	T _J = 125 °C	0.76					
Maximum reverse leakage current per leg	I _{BM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	0.3	mA				
See fig. 2	IRM \''	T _J = 125 °C	$v_{\rm R} = naleu v_{\rm R}$	25					
Threshold voltage	V _{F(TO)}	T T movingum	·	0.38	V				
Forward slope resistance	r _t	$T_J = T_J maximum$	5.75	mΩ					
Maximum junction capacitance per leg	CT	$V_{R} = 5 V_{DC}$ (test signal range	1300	pF					
Typical series inductance per leg	L _S	Measured lead to lead 5 mm	7.5	nH					
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs					

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANIC	THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Maximum junction and storage temperature range	T _J , T _{Stg}		- 55 to 175	°C					
Maximum thermal resistance, junction to case per leg	Р	DC operation See fig. 4	0.8						
Maximum thermal resistance, junction to case per package	nthJC	R _{thJC} DC operation		°C/W					
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.25						
Approvimeto weight			6	g					
Approximate weight			0.21	oz.					
	inimum		6 (5)	kgf · cm					
Mounting torque ma	aximum		12 (10)	(lbf ⋅ in)					
Marking device		Case style TO-247AC (JEDEC)	63CP0	2100G					

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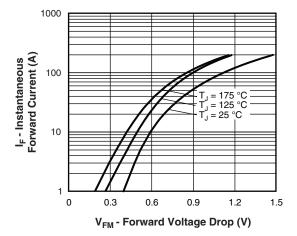
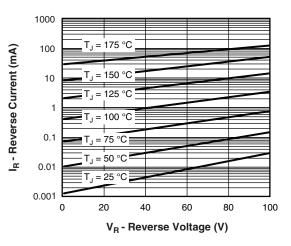
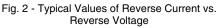


Fig. 1 - Maximum Forward Voltage Drop Characteristics





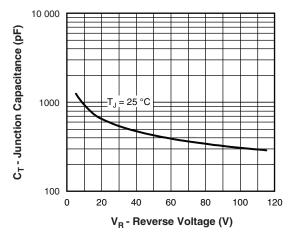
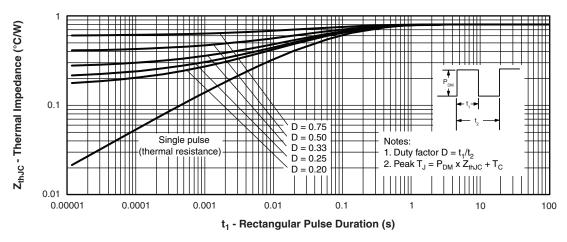


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage





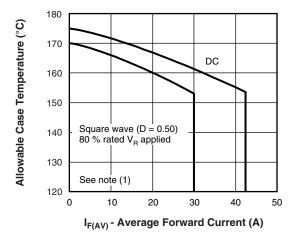
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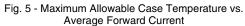


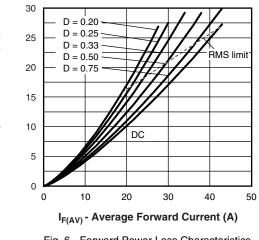
VS-63CPQ100GPbF, VS-63CPQ100G-N3

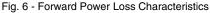
Average Power Loss (W)

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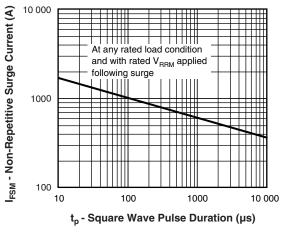


Fig. 7 - Maximum Non-Repetitive Surge Current

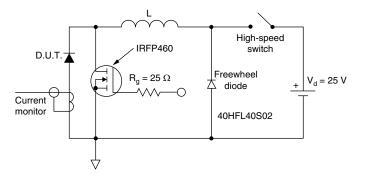


Fig. 8 - Unclamped Inductive Test Circuit

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}/D$) (see fig. 6); Pd_{REV} = Inverse power loss = $V_{R1} \times I_{R}$ (1 - D); I_{R} at V_{R1} = 80 % rated V_{R}

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Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code	VS-	63	С	Р	Q	100	G	PbF
		(2)	(3)	4	(5)	(6)	(7)	(8)
	\odot		J	\bigcirc	9	9		3
	1 -	Visł	nay Sem	niconduc	tors pro	duct		
	2 -	Cur	rent rati	ng (60 A	.)			
	3 -	Circ	uit conf	iguratior	1:			
		C =	Commo	on catho	de			
	4 -	Pac	kage:					
	_	P =	TO-247	,				
	5 -	Sch	ottky "C	" series				
	6 -	Volt	age rati	ng (100	V)			
	7 -	G =	Schottk	ky gener	ation			
	8 -	Env	ironmer	ntal digit				
		• F	bF = Le	ead (Pb)	-free an	d RoHS	compli	ant
		• -	N3 = Ha	logen-fr	ee, RoH	IS comp	oliant, a	nd total

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-63CPQ100GPbF	25		Antistatic plastic tube					
VS-63CPQ100G-N3	25	500	Antistatic plastic tube					

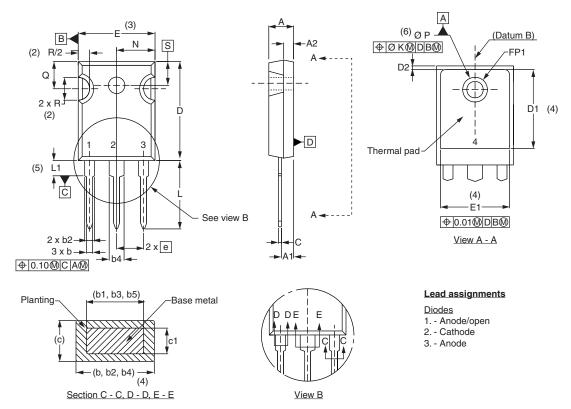
LINKS TO RELATED DOCUMENTS							
Dimensions		www.vishay.com/doc?95223					
Part marking information	TO-247AC PbF	www.vishay.com/doc?95226					
	TO-247AC -N3	www.vishay.com/doc?95007					

Outline Dimensions





DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	MILLIMETERS		HES	NOTES	NOTES		MILLIN	IETERS	INC	HES	NOTES
STNIBOL	MIN.	MAX.	MIN.	MAX.	NOTES		SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209			D2	0.51	1.30	0.020	0.051	
A1	2.21	2.59	0.087	0.102			E	15.29	15.87	0.602	0.625	3
A2	1.50	2.49	0.059	0.098			E1	13.72	-	0.540	-	
b	0.99	1.40	0.039	0.055			e	5.46	BSC	0.215	BSC	
b1	0.99	1.35	0.039	0.053			FK	2.	54	0.0)10	
b2	1.65	2.39	0.065	0.094			L	14.20	16.10	0.559	0.634	
b3	1.65	2.37	0.065	0.094			L1	3.71	4.29	0.146	0.169	
b4	2.59	3.43	0.102	0.135			Ν	7.62	BSC	0	.3	
b5	2.59	3.38	0.102	0.133			ΦP	3.56	3.66	0.14	0.144	
С	0.38	0.86	0.015	0.034			ΦP1	-	6.98	-	0.275	
c1	0.38	0.76	0.015	0.030			Q	5.31	5.69	0.209	0.224	
D	19.71	20.70	0.776	0.815	3		R	4.52	5.49	1.78	0.216	
D1	13.08	-	0.515	-	4		S	5.51	BSC	0.217	BSC	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

- ⁽⁴⁾ Thermal pad contour optional with dimensions D1 and E1
- ⁽⁵⁾ Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

⁽⁷⁾ Outline conforms to JEDEC outline TO-247 with exception of dimension c

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